

/ Descriptions

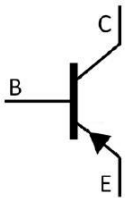
Silicon PNP transistor in a SOT-23 Plastic Package.

/ Features

Low current, low voltage.

/ Applications

General purpose switching and amplifier applications.

/ Equivalent Circuit**/ Pinning**

PIN1 Base PIN 2 Emitter PIN 3 Collector

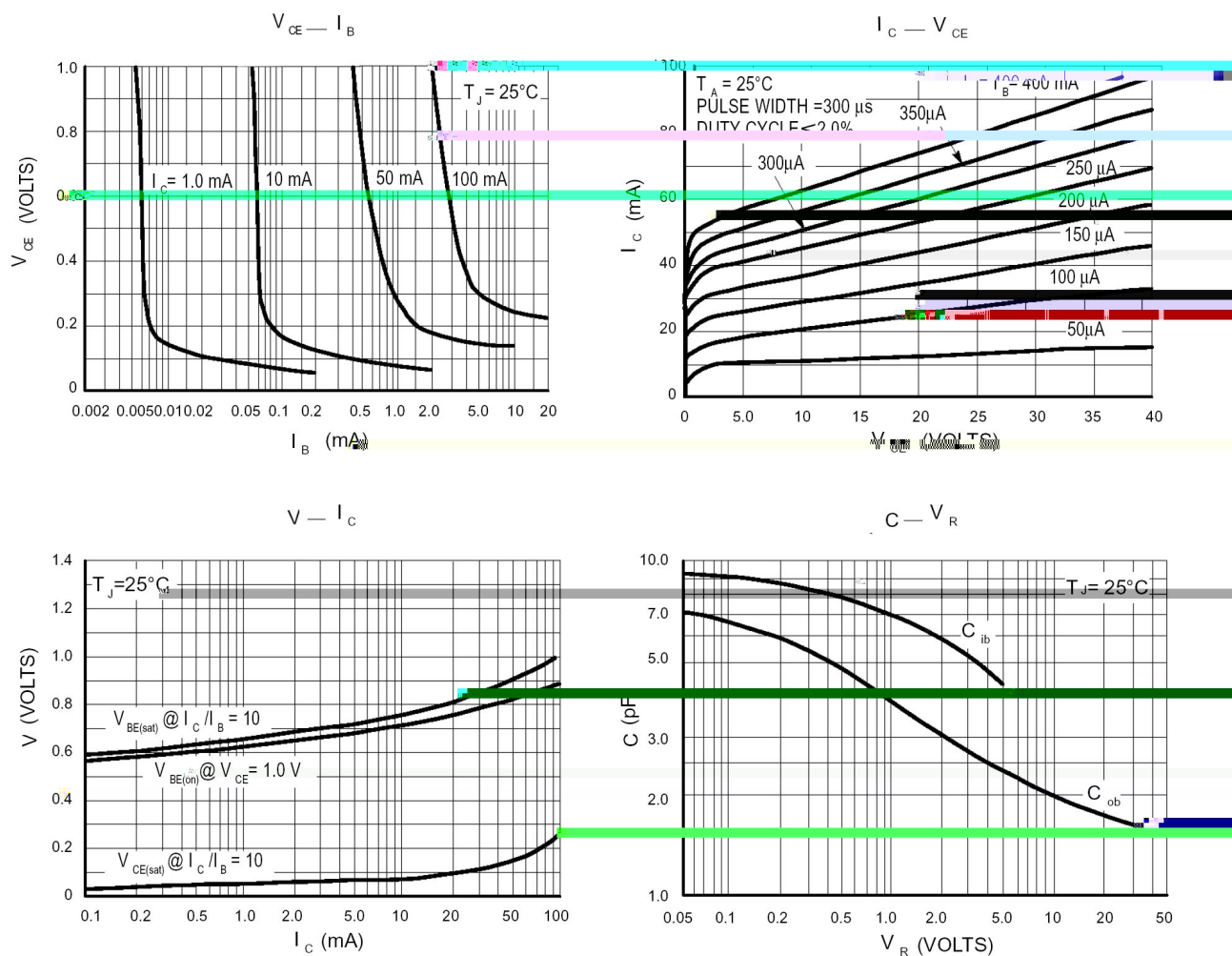
/ h_{FE} Classifications & Marking

h_{FE} Range	215 500
Marking	HH2

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-50	V
Collector to Emitter Voltage	V_{CEO}	-45	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current(DC)	I_C	-100	mA
Peak Collector Current	I_{CM}	-200	mA
Peak Base Current	I_{BM}	-200	mA
Collector Power Dissipation	P_C	250	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C = -100\mu A$ $I_E = 0$	-50			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C = -500\mu A$ $I_B = 0$	-45			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E = -100\mu A$ $I_C = 0$	-5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB} = -20 V$ $I_E = 0$			-0.1	μA
Emitter Base Cut-Off Current	I_{EBO}	$V_{EB} = -5.0V$ $I_C = 0$			-0.1	μA
DC Current Gain	$h_{FE(1)}$	$V_{CE} = -5.0V$ $I_C = -2.0mA$	215		500	
	$h_{FE(2)}$	$V_{CE} = -5.0V$ $I_C = -10\mu A$		150		
Collector to Emitter Saturation Voltage	$V_{CE(sat)(1)}$	$I_C = -10mA$ $I_B = -0.5mA$		-80	-300	mV
	$V_{CE(sat)(2)}$	$I_C = -50mA$ $I_B = -2.5mA$		-150		mV
Base to Emitter Saturation Voltage	$V_{BE(sat)(1)}$	$I_C = -10mA$ $I_B = -0.5mA$		-720		mV
	$V_{BE(sat)(2)}$	$I_C = -50mA$ $I_B = -2.5mA$		-810		mV
Base-Emitter On Voltage	V_{BE}	$V_{CE} = -5.0V$				

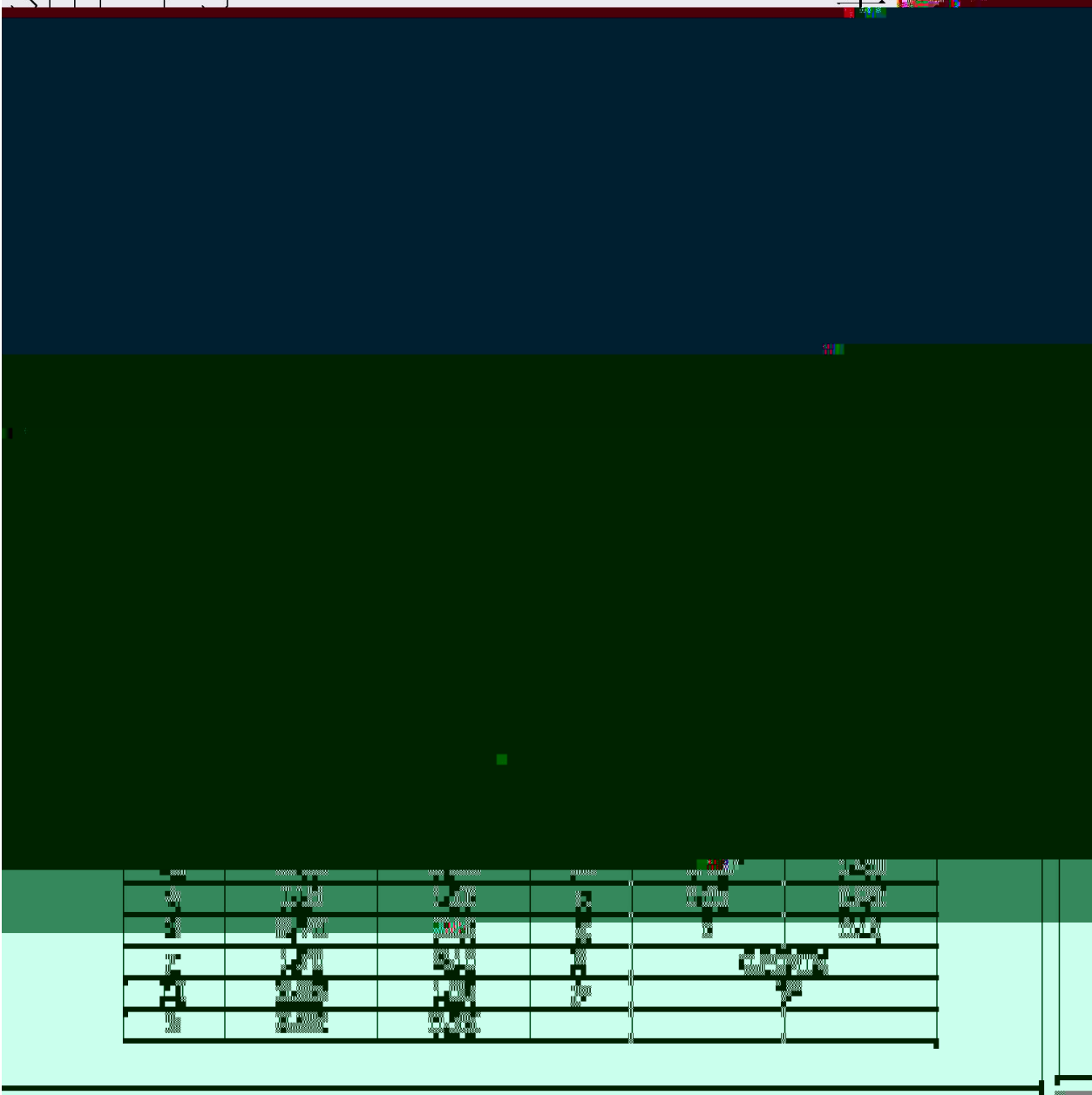
/ Electrical Characteristic Curve



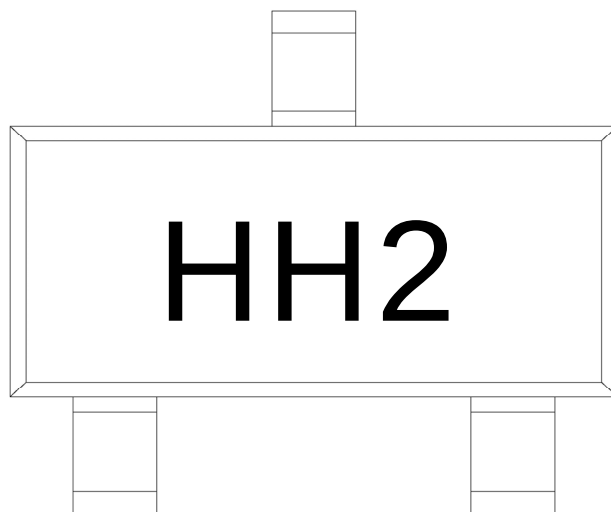
/ Package Dimensions

SOT-23

单位: mm



/ Marking Instructions



H

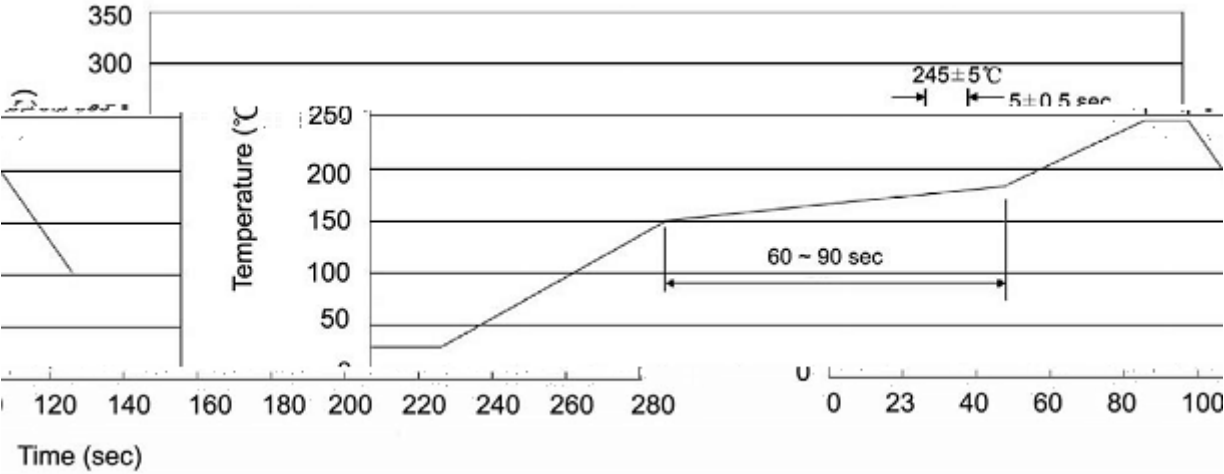
H2

Note:

H: Company Code

H2: Product Type Code

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Note:

- | | | | | | |
|---|-----|-----|----|---------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245 | 5 | 5 | 0.5sec; | 2.Peak Temp.:245 5 , Duration:5 0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

260 5 10 1 sec. Temp.:260 5 Time:10 1 sec

/ Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-23	3,000	10	30,000	6	180,000	7 ×8	180×120×180	390×385×205

/ Notices